

BFQ540 NPN wideband transistor Rev. 05 — 21 March 2013

Product data sheet

1. Product profile

1.1 General description

NPN wideband transistor in a SOT89 plastic package.

1.2 Features and benefits

- High gain
- High output voltage
- Low noise

- Gold metallization ensures excellent reliability
- Low thermal resistance.

1.3 Applications

VHF, UHF and CATV amplifiers.

1.4 Quick reference data

Table 1. Quick reference data

	Quick reference und					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{CBO}	collector-base voltage	open emitter			20	V
V _{CES}	collector-emitter voltage	$R_{BE} = 0$			15	V
V_{EBO}	emitter-base voltage	open collector			2.5	V
l _C	collector current (DC)				120	mA
P _{tot}	total power dissipation	$T_s \le 60 \ ^\circ C$	[1]		1.2	W
h _{FE}	DC current gain	$ I_C = 40 \text{ mA}; V_{CE} = 8 \text{ V}; $	100	120	250	
f _T	transition frequency	$I_{C} = 40 \text{ mA}; V_{CE} = 8 \text{ V};$ f = 1 GHz; T _{amb} = 25 °C		9		GHz
$ s_{21} ^2$	insertion power gain	$\label{eq:lc} \begin{array}{l} I_C = 40 \text{ mA}; \ V_{CE} = 8 \text{ V}; \\ f = 900 \text{ MHz}; \ T_{amb} = 25 \ ^\circ\text{C} \end{array}$	12	13		dB
F	noise figure	$\label{eq:lc} \begin{array}{l} I_{C} = 40 \text{ mA}; \ V_{CE} = 8 \text{ V}; \\ f = 900 \text{ MHz}; \ \Gamma_{S} = \Gamma_{opt} \end{array}$		1.9	2.4	dB

[1] T_s is the temperature at the soldering point of the collector pin.



2. Pinning information

Table 2.	Pinning		
Pin	Description	Simplified outline	Graphic symbol
1	emitter		
2	collector		2
3	base		3

3. Ordering information

Table 3. Ordering information					
Type number	Package				
	Name	Description	Version		
BFQ540	-	plastic surface-mounted package; collector pad for good heat transfer; 3 leads	SOT89		

4. Marking

Table 4.	Marking codes	
Type num	ber	Marking code
BFQ540		N4

5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CBO}	collector-base voltage	open emitter		20	V
V _{CES}	collector-emitter voltage	$R_{BE} = 0$		15	V
V _{EBO}	emitter-base voltage	open collector		2.5	V
I _C	collector current (DC)			120	mA
P _{tot}	total power dissipation	$T_s \le 60 \ ^\circ C$		1.2	W
T _{stg}	storage temperature		-65	+150	°C
Tj	operating junction temperature			175	°C

6. Thermal characteristics

Symbol	Parameter	Conditions	Тур	Unit
R _{th j-s}	thermal resistance from junction to soldering point	$T_s \le 60 \ ^\circ C$; $P_{tot} = 1.2 \ W$	95	K/W
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mbg241 10³ P_{tot} (W) 1.2 I_C (mA) 1.0 0.8 10² 0.6 0.4 0.2 0 ∟ 0 10 ¹⁵⁰ _{Ti} (°C) ²⁰⁰ 10² 50 100 1 10 $V_{CE}(V)$ $V_{CE} \leq 9$ V. Fig 1. Power derating curve. Fig 2. SOAR.

7. Characteristics

Table 7.Characteristics $T_i = 25 \ ^{\circ}C$ unless otherwise specified.

Symbol	Parameter	Conditions	Mi	in Typ	Мах	Unit
V _{(BR)CBO}	collector-base breakdown voltage	open emitter; $I_C = 10 \ \mu A$; $I_E = 0$	20)		V
V _{(BR)CES}	collector-emitter breakdown voltage	$R_{BE} = 0; I_C = 40 \ \mu A$	15	j		V
V _{(BR)EBO}	emitter-base breakdown voltage	$I_E = 100 \ \mu A; I_C = 0$	2			V
I _{CBO}	collector-base leakage current	$V_{CB} = 8 V; I_E = 0$			50	nA
I _{EBO}	emitter-base leakage current	$V_{CB} = 1 V; I_C = 0$			200	nA
h _{FE}	DC current gain	$I_{C} = 40 \text{ mA}; V_{CE} = 8 \text{ V}$	10	0 120	250	
f _T	transition frequency	I_{C} = 40 mA; V_{CE} = 8 V; f_{m} = 1 GHz		9		GHz
C _e	emitter capacitance	$\begin{split} I_{C} &= i_{e} = 0; \ V_{EB} = 0.5 \ V; \\ f &= 1 \ MHz \end{split}$		2		pF
C _{re}	feedback capacitance	$I_{C} = 0; V_{CE} = 8 V; f = 1 MHz$		0.9		pF
s ₂₁ ²	insertion power gain	$\label{eq:IC} \begin{array}{l} I_C = 40 \text{ mA}; \ V_{CE} = 8 \text{ V}; \\ f = 900 \text{ MHz}; \ T_{amb} = 25 \ ^\circ\text{C} \end{array}$	12	13		dB
Vo	output voltage		[1]	500		mV
			[2]	350		mV
d ₂	second order intermodulation distortion		<u>[3]</u>		-53	dB
F	noise figure	$\label{eq:IC} \begin{array}{l} I_C = 40 \text{ mA}; \text{ VCE} = 8 \text{ V}; \\ f = 900 \text{ MHz}; \Gamma_S = \Gamma_{opt} \end{array}$		1.9	2.4	dB
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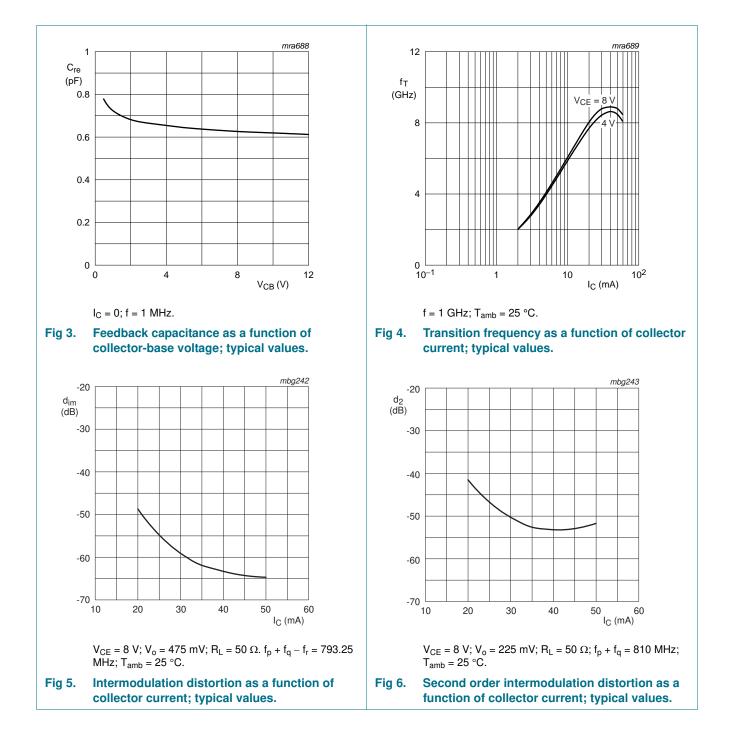
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[1]

- [2] $d_{im} = -60 \text{ dB}$ (DIN 45004B); $I_C = 40 \text{ mA}$; $V_{CE} = 8 \text{ V}$; $R_L = 50 \Omega$; $V_p = V_q = V_o$; $f_p = 806 \text{ MHz}$; $f_q = 810 \text{ MHz}$; measured at $2f_p f_q = 802 \text{ MHz}$.
- [3] $I_C = 40 \text{ mA}$; $V_{CE} = 8 \text{ V}$; $R_L = 50 \Omega$; $V_p = V_q = 225 \text{ mV}$; $f_p = 250 \text{ MHz}$; $f_q = 560 \text{ MHz}$; measured at $f_p + f_q = 810 \text{ MHz}$.



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8. Package outline

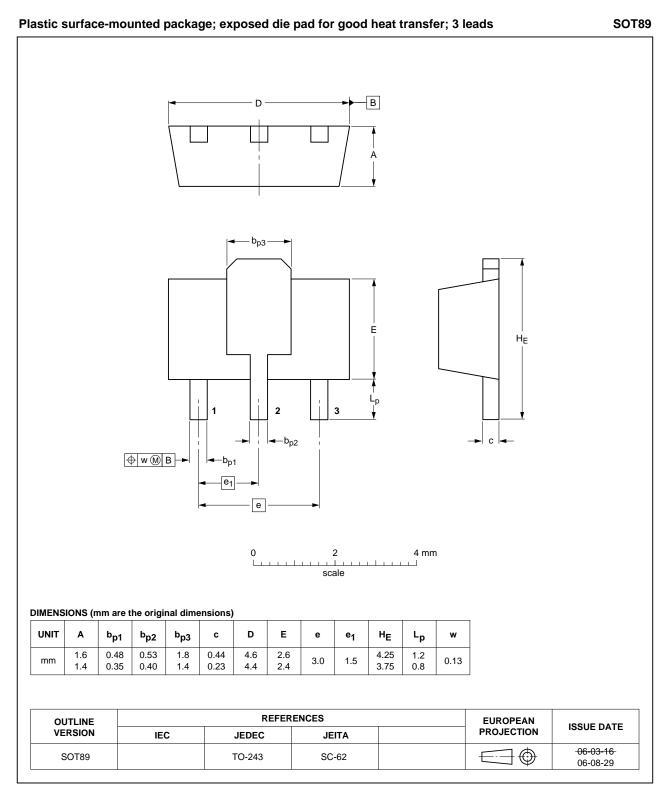


Fig 7. Package outline SOT89 (TO-243).

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9. Revision history

Table 8. Revision	nistory			
Document ID	Release date	Data sheet status	Change notice	Supersedes
BFQ540 v.5	20130321	Product data sheet	-	BFQ540_N_4
Modifications:	guidelines o • Legal texts	of this data sheet has been of NXP Semiconductors. have been adapted to the n utline drawings have been u updated.	ew company name whe	ere appropriate.
BFQ540_N_4	20070925	Product data sheet	-	BFQ540_3
BFQ540_3 (9397 750 07064)	20000523	Product specification		BFQ540_2
BFQ540_2 (9397 750 04296)	19980827	Product specification		BFQ540_1
BFQ540_1	19950904	Product specification		-

10. Legal information

10.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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